



GaAs MMIC I/Q Mixer 8 - 12 GHz

Typical Applications

The HMC1056LP4BE is ideal for:

- Point-to-Point and Point-to-Multi-Point Radio
- Military Radar, EW & ELINT
- Satellite Communications
- Sensors

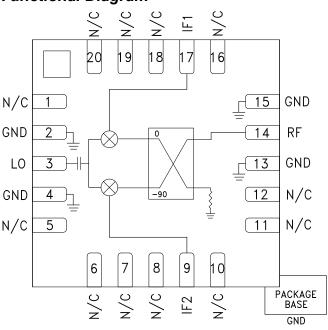
Features

Wide IF Bandwidth: DC - 4 GHz

Image Rejection: 25 dBc LO to RF isolation: 40 dB High Input IP3: 18 dBm

20 Lead 4x4 mm SMT Package: 16 mm²

Functional Diagram



General Description

The HMC1056LP4BE is a compact I/Q MMIC mixer in a leadless "Pb free" SMT package, which can be used as either an Image Reject Mixer or a Single Sideband Upconverter. The mixer utilizes two standard Hittite double balanced mixer cells and a 90 degree hybrid fabricated in a GaAs Schottky diode process. A low frequency quadrature hybrid was used to produce a 100MHz LSB IF output. This product is a much smaller alternative to hybrid style Image Reject Mixers and Single Sideband Upconverter assemblies. The HMC1056LP4BE eliminates the need for wire bonding and allows the use of surface mount manufacturing techniques.

Electrical Specifications, $T_A = +25$ °C, IF = 100 MHz, LSB, LO = +10 dBm [1]

| Parameter | Min. | Тур. | Max. | Min. | Тур. | Max. | Units |
|------------------------------|------|--------|------|------|---------|------|-------|
| Frequency Range, RF/LO | | 8 - 10 | | | 10 - 12 | | GHz |
| Frequency Range, IF | | DC - 4 | | | DC - 4 | | GHz |
| Conversion Loss | | 8 | 11 | | 8 | 11 | dB |
| Image Rejection | 18 | 25 | | 12 | 18 | | dBc |
| LO to RF isolation | 33 | 40 | | 33 | 40 | | dB |
| LO to IF isolation | | 35 | | | 40 | | dB |
| IP3 (input) | | 18 | | | 17 | | dBm |
| Amplitude Balance [2] | | +0.5 | | | +1.5 | | dB |
| Phase Balance ^[2] | | +2.5 | | | -2.5 | | Deg |

^[1] Unless otherwise noted all measurements performed as downconverter.

^[2] Data taken without external 90° hybrid.

HMC1056* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS -

View a parametric search of comparable parts.

EVALUATION KITS

· HMC1056LP4B Evaluation Board

DOCUMENTATION

Data Sheet

• HMC1056 Data Sheet

REFERENCE MATERIALS -

Quality Documentation

- Package/Assembly Qualification Test Report: LP4, LP4B, LP4C, LP4K (QTR: 2013-00487 REV: 04)
- Semiconductor Qualification Test Report: GaAs SD-A (QTR: 2014-00094)

DESIGN RESOURCES 🖵

- HMC1056 Material Declaration
- PCN-PDN Information
- · Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all HMC1056 EngineerZone Discussions.

SAMPLE AND BUY 🖵

Visit the product page to see pricing options.

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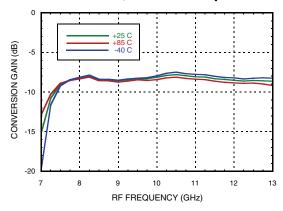




GaAs MMIC I/Q Mixer 8 - 12 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 100 MHz

Conversion Gain, LSB vs. Temperature



Conversion Gain, LSB vs. LO Drive

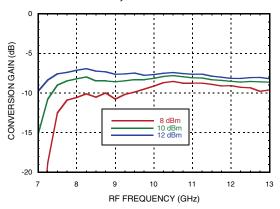


Image Rejection, LSB vs. Temperature

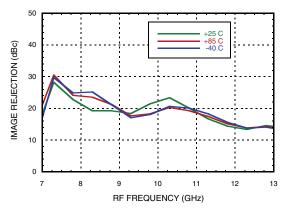
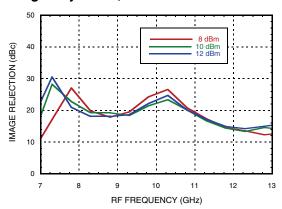
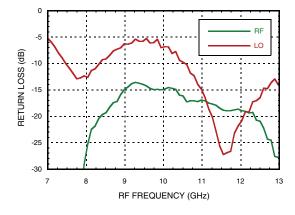


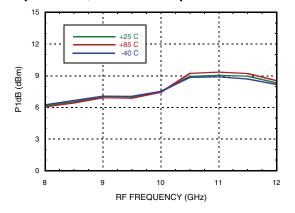
Image Rejection, LSB vs. LO Drive



Return Loss



Input P1dB, LSB vs. Temperature

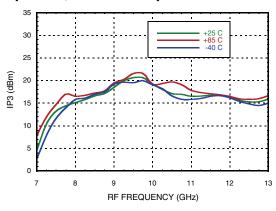


[1] Data taken without external IF 90° hybrid

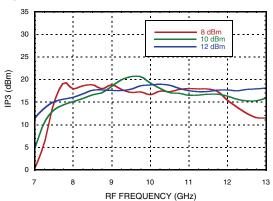


Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 100 MHz

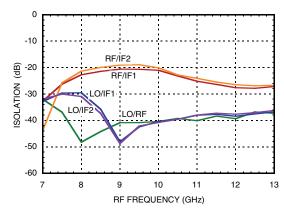
Input IP3, LSB vs. Temperature



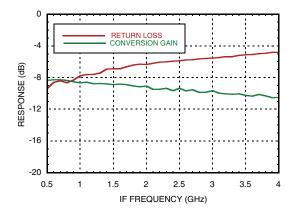
Input IP3, LSB vs. LO Drive



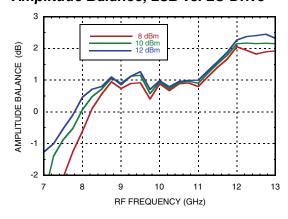
Isolations



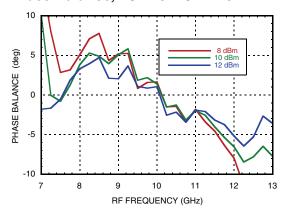
IF Bandwidth*



Amplitude Balance, LSB vs. LO Drive



Phase Balance, LSB vs. LO Drive



^{*} Conversion gain data taken with external IF hybrid.

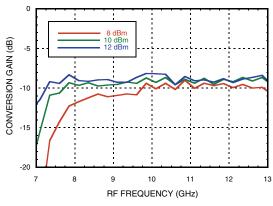




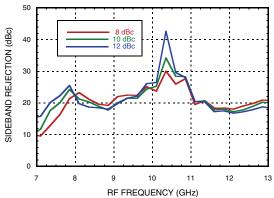
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Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 100 MHz

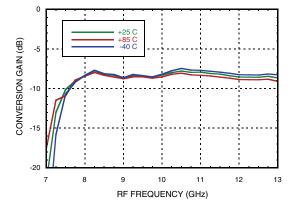
Upconverter Performance, Conversion Gain, LSB vs. LO Drive



Upconverter Performance, Sideband Rejection, LSB vs. LO Drive,



Conversion Gain, USB vs. Temperature



Conversion Gain, USB vs. LO Drive

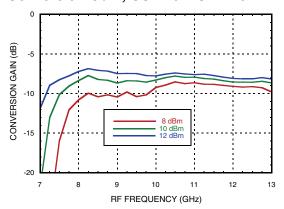


Image Rejection, USB vs. Temperature

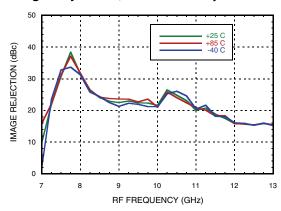
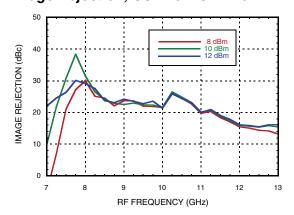


Image Rejection, USB vs. LO Drive

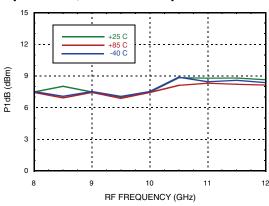




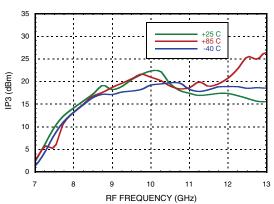
GaAs MMIC I/Q Mixer 8 - 12 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 100 MHz

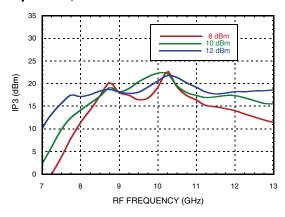
Input P1dB, USB vs. Temperature



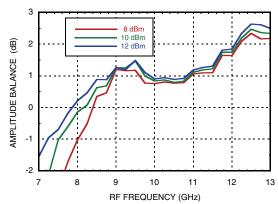
Input IP3, USB vs. Temperature



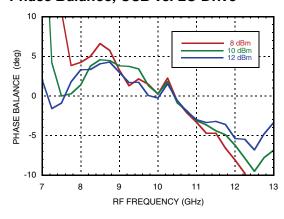
Input IP3, USB vs. LO Drive



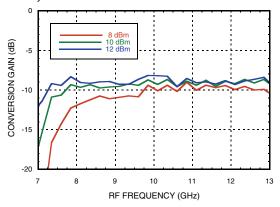
Amplitude Balance, USB vs. LO Drive



Phase Balance, USB vs. LO Drive



Upconverter Performance, Conversion Gain, USB vs. LO Drive



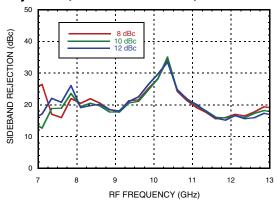




GaAs MMIC I/Q Mixer 8 - 12 GHz

Data Taken as SSB Upconverter with External IF 90° Hybrid, IF = 100 MHz

Upconverter Performance, Sideband Rejection, USB vs. LO Drive,



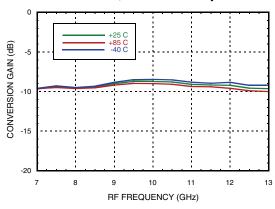




GaAs MMIC I/Q Mixer 8 - 12 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz

Conversion Gain, LSB vs. Temperature



Conversion Gain, LSB vs. LO Drive

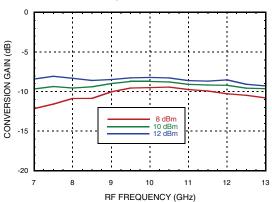


Image Rejection, LSB vs. Temperature

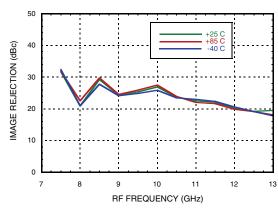
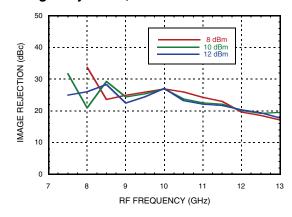
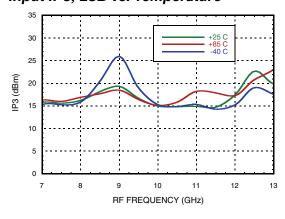


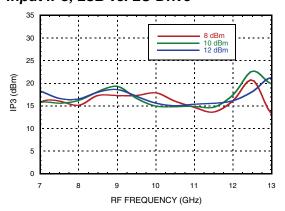
Image Rejection, LSB vs. LO Drive



Input IP3, LSB vs. Temperature



Input IP3, LSB vs. LO Drive

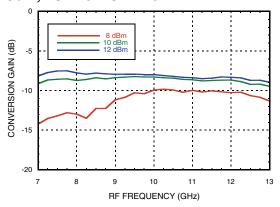




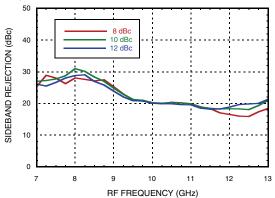
GaAs MMIC I/Q Mixer 8 - 12 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz

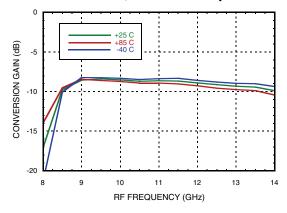
Upconverter Performance, Conversion Gain, LSB vs. LO Drive



Upconverter Performance, Sideband Rejection, LSB vs. LO Drive,



Conversion Gain, USB vs. Temperature



Conversion Gain, USB vs. LO Drive

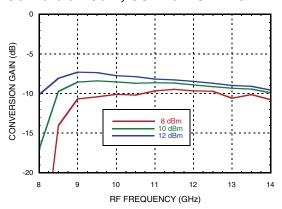


Image Rejection, USB vs. Temperature

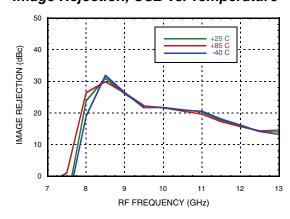
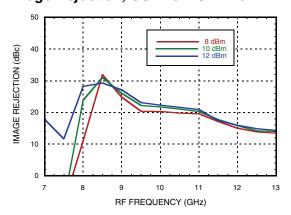


Image Rejection, USB vs. LO Drive



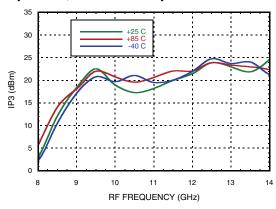




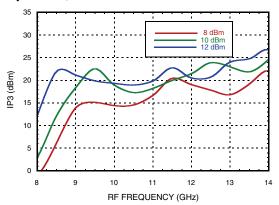
GaAs MMIC I/Q Mixer 8 - 12 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz

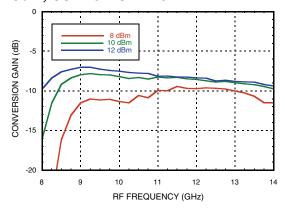
Input IP3, USB vs. Temperature



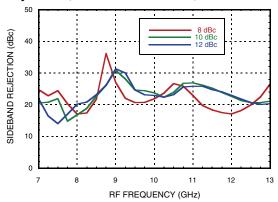
Input IP3, USB vs. LO Drive



Upconverter Performance, Conversion Gain, USB vs. LO Drive



Upconverter Performance, Sideband Rejection, USB vs. LO Drive,

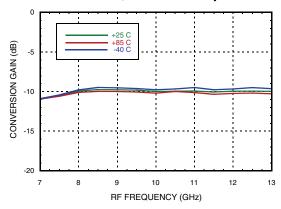




GaAs MMIC I/Q Mixer 8 - 12 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 2000 MHz

Conversion Gain, LSB vs. Temperature



Conversion Gain, LSB vs. LO Drive

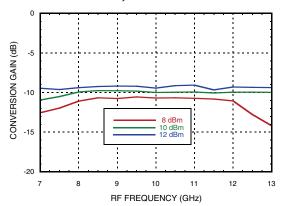


Image Rejection, LSB vs. Temperature

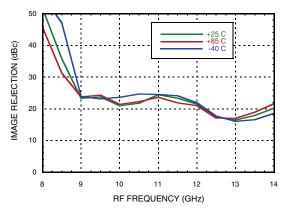
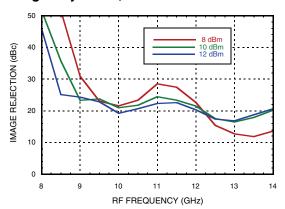
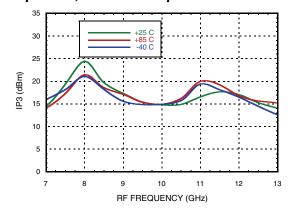


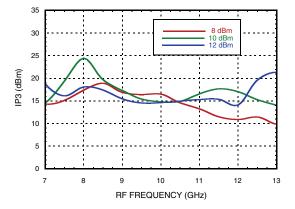
Image Rejection, LSB vs. LO Drive



Input IP3, LSB vs. Temperature

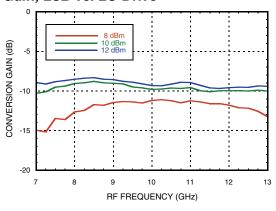


Input IP3, LSB vs. LO Drive

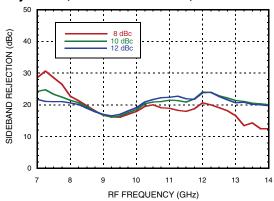


Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 2000 MHz

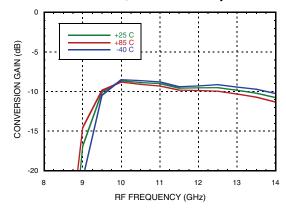
Upconverter Performance, Conversion Gain, LSB vs. LO Drive



Upconverter Performance, Sideband Rejection, LSB vs. LO Drive,



Conversion Gain, USB vs. Temperature



Conversion Gain, USB vs. LO Drive

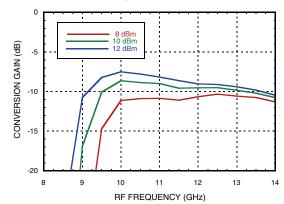


Image Rejection, USB vs. Temperature

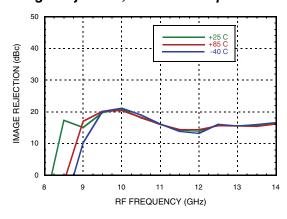
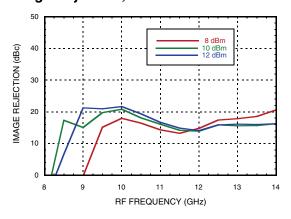


Image Rejection, USB vs. LO Drive

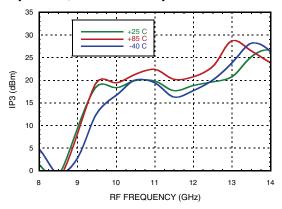




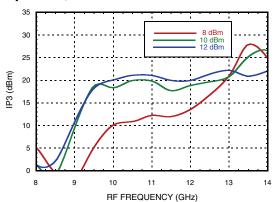


GaAs MMIC I/Q Mixer 8 - 12 GHz

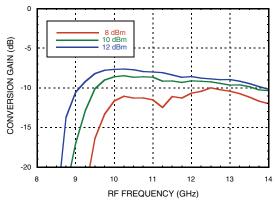
Input IP3, USB vs. Temperature



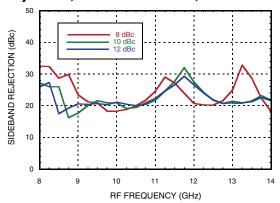
Input IP3, USB vs. LO Drive



Upconverter Performance, Conversion Gain, USB vs. LO Drive



Upconverter Performance, Sideband Rejection, USB vs. LO Drive,



Harmonics of LO

| LO Fron (CHT) | nLO Spur at RF Port | | | | | |
|----------------|---------------------|------|------|-------|--|--|
| LO Freq. (GHz) | 1 | 2 | 3 | 4 | | |
| 7 | 41.3 | 37.6 | 74.4 | 74.2 | | |
| 8 | 36.3 | 36.3 | 52 | 82.1 | | |
| 9 | 37.2 | 52.9 | 63.6 | 81.4 | | |
| 10 | 36.8 | 56.4 | 65.5 | 100.4 | | |
| 11 | 37.3 | 59.8 | 68.9 | 68.8 | | |
| 12 | 37.4 | 56.2 | 65.3 | 78.9 | | |
| 13 | 38.1 | 56.4 | 69.6 | х | | |

LO = + 10 dBm

Values in dBc below LO level measured at RF Port.

MxN Spurious Outputs

| | nLO | | | | |
|-----|-----|----|----|----|----|
| mRF | 0 | 1 | 2 | 3 | 4 |
| 0 | xx | 8 | 38 | 48 | 60 |
| 1 | 8 | 0 | 28 | 43 | 60 |
| 2 | 64 | 50 | 56 | 48 | 67 |
| 3 | 94 | 78 | 67 | 64 | 78 |
| 4 | х | х | х | х | х |

RF = 10 GHz @ -10 dBm

LO = 10.1 GHz @ +10 dBm

Data taken without IF hybrid

All values in dBc below IF power level





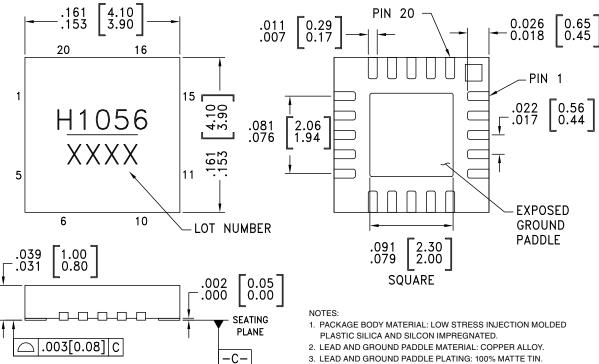
GaAs MMIC I/Q Mixer 8 - 12 GHz

Absolute Maximum Ratings

| IF Input (At LO = 10 dBm and RF = -10 dBm) | +15.5 dBm | |
|--|----------------------|--|
| RF Input (At 10 dBm LO power) | +16 dBm | |
| LO Input (At -10 dBm RF power) | +17 dBm | |
| Channel Temperature | 175 °C | |
| Continuous Pdiss (T = 85°C) (derate 8.9 mW/°C above 85°C) | 800 mW | |
| Thermal Resistance (channel to ground paddle) | 112 °C/W | |
| Storage Temperature | -65 to +150 °C | |
| Operating Temperature | -40 to +85 °C | |
| ESD Sensitivity (HBM) | Class 0, Passed 150V | |



Outline Drawing



- 3. LEAD AND GROUND PADDLE PLATING: 100% MATTE TIN.
- 4. DIMENSIONS ARE IN INCHES [MILLIMETERS].
- 5. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
- 6. PAD BURR LENGTH SHALL BE 0.15mm MAX. PAD BURR HEIGHT SHALL BE 0.05mm MAX.
- 7. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 8. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB BE GROUND

Package Information

| I | Part Number | Package Body Material | Lead Finish | MSL Rating [2] | Package Marking [1] |
|---|--------------|--|---------------|----------------|----------------------|
| | HMC1056LP4BE | RoHS-compliant Low Stress Injection Molded Plastic | 100% matte Sn | MSL1 | <u>H1056</u> XXXX |

^{[1] 4-}Digit lot number XXXX

^[2] Max peak reflow temperature of 260 °C





GaAs MMIC I/Q Mixer 8 - 12 GHz

Pin Descriptions

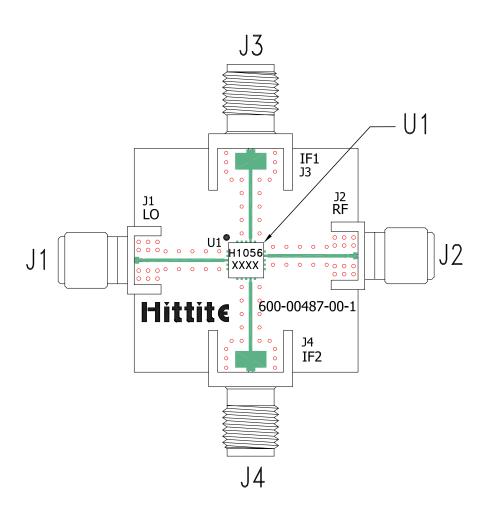
| Pin Number | Function | Description | Interface Schematic |
|-----------------------------|----------|---|---------------------|
| 1, 5-8, 10-12, 16, 18-20 | N/C | These pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally. | |
| 2, 4, 13, 15 | GND | These pins and the exposed ground paddle must be connected to RF/DC ground. | ○ GND = |
| 3 | LO | This pin is AC coupled and matched to 50 Ohms . | L0 ○──── |
| 9 | IF2 | Differential IF input pins. For applications not requiring operation to DC, an off chip DC blocking capacitor should | IF1,IF2 O |
| 17 | IF1 | be used. For operation to DC this pin must not source/sink more than 3mA of current or part non function and possible part failure will result. | |
| 14 | RF | This pin is matched to 50 Ohms. | RF ○── |





GaAs MMIC I/Q Mixer 8 - 12 GHz

Evaluation PCB



List of Materials for Evaluation PCB EVAL01-HMC1056LP4B[1]

| Item | Description | |
|---------|----------------------------------|--|
| J1, J2 | PCB Mount SMA RF Connector, SRI | |
| J3 - J4 | PCB Mount SMA Connector, Johnson | |
| U1 | HMC1056LP4BE | |
| PCB [2] | 600-00487-00-1 Evaluation Board | |

^[1] Reference this number when ordering complete evaluation PCB

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

^[2] Circuit Board Material: Rogers 4350



MIXERS - I/Q MIXERS, IRMS & RECEIVERS - SMT

ANALOGDEVICES



Notes:

GaAs MMIC I/Q Mixer 8 - 12 GHz